Transisto 都面DTB123E供应商

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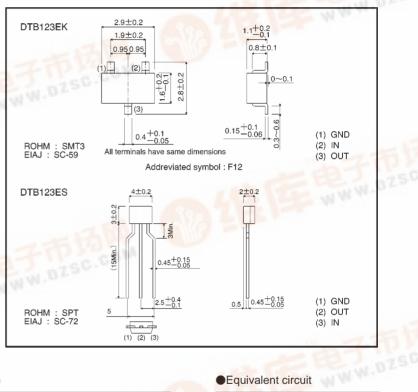
Digital transistors (built-in resistors) DTB123EK / DTB123ES

External dimensions (Units: mm)

Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

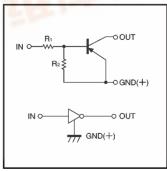
Structure PNP digital transistor (Built-in resistor type)



•Absolute maximum ratings (Ta = 25° C)

Deremeter	Ourseland.	Limits(D1	Linit		
Parameter	Symbol	К	S	Unit	
Supply voltage	Vcc	-5	0C1	V	
Input voltage	VIN	WH-1	V		
		-1			
Output current	lc	-500		mA	
Power dissipation	Pd	200	300	mW	
Junction temperature	Tj	150		Ĵ	
Storage temperature	Tstg	-55~+150		°C	

Equivalent circuit



Transistors

• Electrical characteristics (Ta = 25° C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	VI(off)	_	_	-0.5	v	$V_{CC} = -5V$, $I_{O} = -100 \mu A$
	VI(on)	-3	_	_		$V_0 = -0.3V$, $I_0 = -20mA$
Output voltage	VO(on)	—	_	-0.3	V	lo/l=-50mA/-2.5mA
Input current	h	—	_	-3.8	mA	V1=-5V
Output current	O(off)	—	—	-0.5	μA	$V_{CC} = -50V, V_I = 0V$
DC current gain	Gi	39	_	_	_	Vo=-5V, Io=-50mA
Input resistance	R1	1.54	2.2	2.86	kΩ	—
Resistance ratio	R2/R1	0.8	1	1.2	_	_
Transition frequency	fт	—	200	_	MHz	Vce=-10V, Ie=5mA, f=100MHz *

* Transition frequency of the device

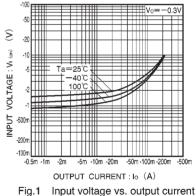
Packaging specifications

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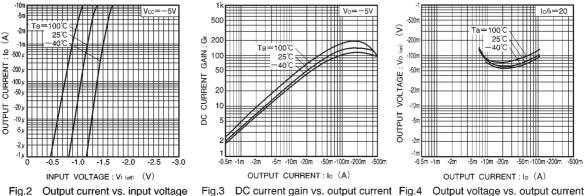
OUTPUT CURRENT

	Package	SMT3	SPT
	Packaging type	Taping	Taping
	Code	T146	TP
Part No.	Basic ordering unit (pieces)	3000	5000
DTB123EK		0	_
DTB123ES		_	0

Electrical characteristic curves



(ON characteristics)



(OFF characteristics)

Fig.3 DC current gain vs. output current Fig.4 Output voltage vs. output current